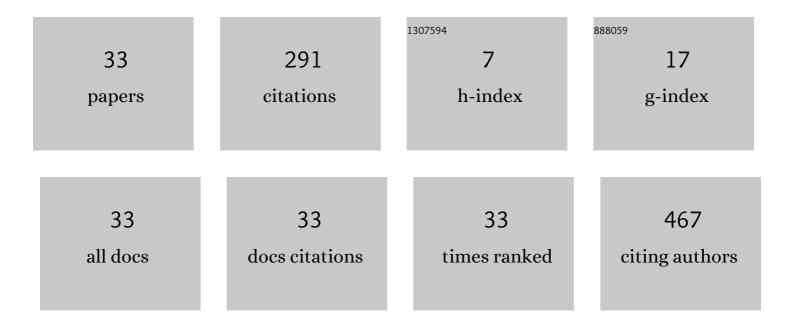
Nilakantha Tripathy

List of Publications by Year in descending order

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#	Article	IF	CITATIONS
1	Role of Gd dopants on electrical properties of RF co-sputtered HfO2 thin films for resistive switching applications. Materials Science and Engineering B: Solid-State Materials for Advanced Technology, 2021, 265, 114997.	3.5	2
2	Structural and morphological study of thermally oxidized titanium thin films for the detection of chlorpyrifos. Materials Science in Semiconductor Processing, 2020, 105, 104695.	4.0	2
3	Morphological and electrical characterizations of dip coated porous TiO2 thin films with different concentrations of thiourea additives for resistive switching applications. Journal of Materials Science: Materials in Electronics, 2019, 30, 15928-15934.	2.2	2
4	Enhanced organophosphate sensing response of copper incorporated ZnO nanowires. Materials Science in Semiconductor Processing, 2019, 104, 104675.	4.0	4
5	Morphological and electrical properties of RF sputtered calcium copper titanate thin films with the incorporation of intermediate layer. Ceramics International, 2019, 45, 23993-24000.	4.8	2
6	High dielectric constant, low loss and efficient visible photoluminescence properties of porous rose- flower shaped CoFe2O4 for photovoltaic application. Materials Letters, 2019, 242, 62-65.	2.6	4
7	Limited volume heating method: a simple low cost approach to synthesize additive free long nanowires. Journal of Materials Science: Materials in Electronics, 2019, 30, 5065-5073.	2.2	3
8	Room Temperature Organophosphate Detection by Thermally Oxidized Metal Oxide Thin Films. Springer Proceedings in Physics, 2019, , 849-854.	0.2	0
9	Electrical characteristics of dip coated TiO2 thin films with various withdrawal speeds for resistive switching applications. Applied Surface Science, 2018, 449, 181-185.	6.1	16
10	Impact of post-deposition annealing on RF sputtered calcium copper titanate thin film for memory application. Materials Research Express, 2018, 5, 074001.	1.6	6
11	Transformation of sputtered calcium copper titanate thin film into nanorods by sequential annealing. Ceramics International, 2018, 44, 4052-4057.	4.8	5
12	Effect of Process Temperature on Molybdenum Disulphide Layers Grown by Chemical Vapor Deposition Technique. , 2018, , .		2
13	Resistive Switching Behavior of RF Sputtered Calcium Copper Titanate Thin Films with Various Annealing Approach. , 2018, , .		1
14	Reduced graphene oxide-CuFe2O4 nanocomposite: A highly sensitive room temperature NH3 gas sensor. Sensors and Actuators B: Chemical, 2018, 272, 100-109.	7.8	110
15	Optical & current-voltage characteristics of dip coated TiO2thin film. IOP Conference Series: Materials Science and Engineering, 2018, 338, 012058.	0.6	0
16	Effect of RF sputtering power on morphological and electrical properties of calcium copper titanate thin films. Journal of Materials Science: Materials in Electronics, 2017, 28, 11401-11405.	2.2	10
17	Modulation of microstructure and interface properties of co-sputter derived Hf1â^'xTixO2 thin films with various Ti content. Journal of Materials Science: Materials in Electronics, 2017, 28, 12408-12414.	2.2	3
18	Microstructural, surface and interface properties of zirconium doped HfO2 thin films grown by RF co-sputtering technique. Vacuum, 2017, 143, 288-293.	3.5	14

NILAKANTHA TRIPATHY

#	Article	IF	CITATIONS
19	Reduction of oxide and interface charge density of reactive sputtered HfO2 thin films by rapid thermal annealing. AIP Conference Proceedings, 2017, , .	0.4	1
20	Synthesis of copper doped Zinc oxide nanowires with enhanced ultraviolet photoresponse behavior. IOP Conference Series: Materials Science and Engineering, 2017, 178, 012021.	0.6	7
21	Investigation of microstructural and electrical properties of composition dependent co-sputtered Hf1â°'xTaxO2thin films. Materials Research Express, 2017, 4, 114007.	1.6	1
22	Investigation of surface and interface properties of RF sputtered calcium copper titanate thin films on silicon substrate. Journal of Materials Science: Materials in Electronics, 2017, 28, 2686-2690.	2.2	6
23	Effect of rapid thermal annealing on the structural and electrical properties of RF sputtered CCTO thin film. IOP Conference Series: Materials Science and Engineering, 2017, 178, 012009.	0.6	1
24	Morphological evolution of zinc oxide thin films with variation in sputtering power and substrate temperature. International Journal of Microstructure and Materials Properties, 2016, 11, 325.	0.1	0
25	Effect of post-deposition annealing on the structural and electrical properties of RF sputtered hafnium oxide thin films. IOP Conference Series: Materials Science and Engineering, 2016, 115, 012015.	0.6	0
26	Ultraviolet photodetection characteristics of Zinc oxide thin films and nanostructures. IOP Conference Series: Materials Science and Engineering, 2016, 115, 012035.	0.6	44
27	Fabrication of high-k dielectric Calcium Copper Titanate (CCTO) target by solid state route. IOP Conference Series: Materials Science and Engineering, 2016, 115, 012022.	0.6	7
28	Evolution of microstructural and electrical properties of sputtered HfO2 ceramic thin films with RF power and substrate temperature. Ceramics International, 2016, 42, 138-145.	4.8	19
29	Morphological evolution of zinc oxide thin films with variation in sputtering power and substrate temperature. International Journal of Microstructure and Materials Properties, 2016, 11, 325.	0.1	1
30	Effect of substrate temperature on structural and electrical properties of RF sputtered hafnium oxide thin films. AIP Conference Proceedings, 2015, , .	0.4	1
31	Surface and interface studies of RF sputtered HfO2 thin films with working pressure and gas flow ratio. Journal of Materials Science: Materials in Electronics, 2015, 26, 6025-6031.	2.2	7
32	Morphological and Photoluminescence analysis of Zinc Oxide thin films deposited by RF sputtering at different substrate temperatures. IOP Conference Series: Materials Science and Engineering, 2015, 75, 012023.	0.6	1
33	Microstructural evolution of sputtered ZnO thin films with rapid thermal annealing. Journal of Materials Science: Materials in Electronics, 2015, 26, 7860-7866.	2.2	9